



Contribution ID: 528

Type: **Poster Presentation**

Synthesis and characterization of tin oxide nanostructures for gas sensing applications

Tuesday, 9 July 2013 17:40 (1 hour)

**Abstract content
 (Max 300 words)**

Tin oxide (SnO₂) is an important wide-bandgap (3.6 eV) n-type semiconductor with a rutile structure which has received a great deal of attention over the past few years due to its high transparency in the visible part of the spectrum, structural and chemical stability. It has been investigated for advanced functional use such as solid state gas sensors, transparent conductors, oxidation catalysts and optoelectronic devices. In this work we report on the successful formation of SnO₂ nanostructures by using the Chemical vapour deposition process. As synthesized SnO₂ samples were characterized using scanning electron microscopy (SEM), X-ray powder diffraction (XRD), and nitrogen adsorption analysis (BET). X-ray analysis of the tin oxide nanomaterial showed a highly, pure crystalline material

**Apply to be
 considered for a student
 award (Yes / No)?**

yes

**Level for award
 (Hons, MSc,
 PhD)?**

MSc

**Main supervisor (name and email)
and his / her institution**

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**Would you like to
 submit a short paper
 for the Conference
 Proceedings (Yes / No)?**

no

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